Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	6247	(cross-link cross-linked cross-linking) with UV	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 16:23
L3	4	(US-20050008880-\$ or US-20050161666-\$).did. or (US-5178959-\$ or US-6259506-\$). did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 16:22
L5	4	(US-20050008880-\$ or US-20050161666-\$).did. or (US-5178959-\$ or US-6259506-\$). did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 16:23
L6	1886	surface-coordinat\$3 or surface adj coordinat\$3	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 16:30
17	3837	nanocrystal	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	ΘR	ON	2006/08/12 16:25
L8	22865	nanocrystal nanoparticle	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 16:25
L9	19	6 and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR .	ON	2006/08/12 16:56
L10	6	6 with 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 16:25
L11	627	(Alivisatos scher manna) and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12_16:58
L12	90	(Alivisatos scher manna).in. and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:18

L13	68	12 and (surface surfactant)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:08
L14	66	12 and (surface surfactant) with 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:08
L15	6043	(surface surfactant) with 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:08
L16	23-	12 and 15 and (pattern patterning patterned)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:09
L17	18	(Alivisatos scher manna).in. and expos\$3 with (mask reticule pattern)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:26
L18	4959	light-emitting and expos\$3 with (mask reticule pattern)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	ΘR	ON	2006/08/12 17:26
L19	326	light-emitting and exposing with (mask reticule pattern) same developing	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:27
L20	27	organic adj light-emitting and exposing with (mask reticule pattern) same developing	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON.	2006/08/12-17:29
L21	238	(crosslinked crosslink crosslinking cross-linked cross-link cross-linking) same exposing with (mask reticule pattern) same developing	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:30
L31	7.	"5,534,056" and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 17:55

						
L32	15	"5,534,056"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 17:55
L33	6	(US-20040118448-\$ or US-20050051769-\$ or US-20040095658-\$).did. or (US-5434878-\$ or US-5253258-\$ or US-3984500-\$).did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 19:35
L34	17	(US-20030226498-\$ or US-20030170959-\$ or US-20030145779-\$ or US-20040155517-\$ or US-20040039201-\$ or US-20050002635-\$ or US-20020155507-\$ or US-20020114998-\$ or US-20040115817-\$).did. or (US-6602671-\$ or US-6512172-\$ or US-6319426-\$ or US-6207392-\$ or US-5825790-\$ or US-5625456-\$ or US-5559057-\$ or US-5751018-\$). did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 19:35
L35	15	L34 and ((CdS CdSe CdTe ZnS ZnSe ZnTe HgS HgSe HgTe GaN GaP GaAs InP InAs) or (cadmium zinc mercury) adj (sulfide selenide telluride) or (gallium indium) adj (nitride phosphide arsenide))	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L36	3	L35 and (photocurable photocured cured photocuring curing curable)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L37	3	(("5,448,582") or ("5,434,878") or ("6259506")).PN	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/12 19:35
L38	3	L37 and (uv or light)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L39	15	L34 and ((CdS CdSe CdTe ZnS ZnSe ZnTe HgS HgSe HgTe GaN GaP GaAs InP InAs) or (cadmium zinc mercury) adj (sulfide selenide telluride) or (gallium indium) adj (nitride phosphide arsenide))	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L40	1894	UV with (cured curing curable) with energy	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35

139	UV with (cured curing curable) with joule	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35
954	UV with (cured curing curable) with (millijoule mj joule)	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35
6958	((257/40) or (428/447)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/12 19:35
7	semiconductor nanocrystal same -cur\$3	US-PGPUB; USPAT	.ADJ	OFF	2006/08/12 19:35
113	semiconductor adj nanocrystal and (cured curing curable)	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35
8	"6,114,038" and (cured curing curable)	US-PGPUB; USPAT	OŘ	ON	2006/08/12 19:35
143	semiconductor nanocrystal.clm.	US-PGPUB; USPAT	ADJ	OFF	2006/08/12 19:35
132	UV with (cured curing curable) with (millijoule mj joule) with resin	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35
408	semiconductor nanocrystal	US-PGPUB; USPAT	ADJ	OFF	2006/08/12 19:35
6247	(cross-link cross-linked cross-linking) with UV	US-PGPUB; USPAT; EPO; DERWENT;	OR	OFF	2006/08/12 19:35
113	semiconductor adj nanocrystal and	US-PGPUB;	OR	ON	2006/08/12 19:35
30	(cured curing curable) L51 and polymer with (cured curing curable)	USPAT USPAT	OR-	ON	2006/08/12 19:35
14	(cross-link cross-linked cross-linking) and L52	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
11	L53 and solvent	US-PGPUB;	OR	ON	2006/08/12 19:35
		EPO; DERWENT; IBM_TDB			
11	L54 and cross	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 19:35
113	semiconductor adj nanocrystal and (cured curing curable)	US-PGPUB; USPAT	OR	ON	2006/08/12-19:35
30	L51 and polymer with (cured curing curable)	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35
	954 6958 7 113 8 143 132 408 6247 113 111 111	joule UV with (cured curing curable) with (millijoule mj joule) ((257/40) or (428/447)).CCLS. remiconductor nanocrystal same cur\$3 semiconductor adj nanocrystal and (cured curing curable) "6,114,038" and (cured curing curable) with (millijoule mj joule) with resin semiconductor nanocrystal UV with (cured curing curable) with (millijoule mj joule) with resin semiconductor nanocrystal (cross-link cross-linked cross-linked cross-linking) with UV semiconductor adj nanocrystal and (cured curing curable) 113 semiconductor adj nanocrystal and (cured curing curable) 14 (cross-link cross-linked cross-linking) and L52 15 and solvent L54 and cross semiconductor adj nanocrystal and (cured curing curable) 15 and solvent L54 and cross	Joule UV with (cured curing curable) with (millijoule mj joule) ((257/40) or (428/447)).CCLS. For incomplete curists are cursts are curable) Begin and (cured curing curable) Begin and (cured curing curable) Curable are semiconductor nanocrystal and (cured curing curable) UV with (cured curing curable) with (millijoule mj joule) with resin semiconductor nanocrystal Cuross-link cross-linked cross-linking) with UV Semiconductor adj nanocrystal and (cured curing curable) Curable are curing curable uspart US-PGPUB; USPAT US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	joule UV with (cured curing curable) with (millijoule mj joule) ((257/40) or (428/447)).CCLS. Semiconductor nanocrystal same cur\$3 113 semiconductor adj nanocrystal and (cured curing curable) 8 "6,114,038" and (cured curing curable) WIS-PGPUB; USPAT 143 semiconductor nanocrystal.clm. 144 UV with (cured curing curable) with (millijoule mj joule) with resin semiconductor and nanocrystal and (cured curing curable) 115 semiconductor nanocrystal 116 (cross-link cross-linked cross-linking) with UV 117 Semiconductor adj nanocrystal and (cured curing curable) 118 semiconductor adj nanocrystal and (cured curing curable) 119 (cross-link cross-linked cross-linking) and L52 110 L53 and solvent 111 L54 and cross 112 L54 and cross 113 semiconductor adj nanocrystal and (cured curing curable) 114 (cross-link cross-linked cross-linking) and L52 US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB 115 L54 and cross US-PGPUB; OR USPAT; EPO; DERWENT; IBM_TDB 116 L54 and cross US-PGPUB; OR USPAT; EPO; DERWENT; IBM_TDB US-PGPUB; OR USPAT	joule 954 UV with (cured curing curable) with (millijoule mj joule) 7 semiconductor nanocrystal same cur\$3 113 semiconductor adj nanocrystal and (cured curing curable) 143 semiconductor nanocrystal.clm. 154 uV with (cured curing curable) with (millijoule mj joule) with resin semiconductor adj nanocrystal and (cross-link cross-linked cross-linking) with UV 155 and polymer with (cured curing curable) 151 L53 and solvent 152 uV with (cured curing curable) 153 aemiconductor adj nanocrystal and (cured curing curable) 154 and cross 155 and solvent 156 and cross 157 and polymer with (cured curing curable) 158 and cross 159 and polymer with (cured curing curable) 151 and polymer with (cured curing curable) 152 and solvent 153 and solvent 154 and cross 155 and polymer with (cured curing curable) 156 and polymer with (cured curing curable) 157 and polymer with (cured curing curable) 158 and cross 159 and cross 150 and polymer with (cured curing curable) 151 and polymer with (cured curing curable) 153 and cross 154 and cross 155 and polymer with (cured curing curable) 155 and polymer with (cured curing curable) 156 and polymer with (cured curing curable) 157 and polymer with (cured curing curable) 158 and polymer with (cured curing curable) 159 and polymer with (cured curing curable) 151 and polymer with (cured curing curable) 155 and polymer with (cured curing curable) 156 and polymer with (cured curing curable) 157 and polymer with (cured curing curable) 158 and polymer with (cured curing curable) 159 and polymer with (cured curing curable) 150 and polymer with (cured curing curable) 151 and polymer with (cured curing curable) 152 and polymer with (cured curing curable) 153 and polymer with (cured curing curable) 154 and polymer with (cured curing curable) 155 and polymer with (cured curing curable) 156 and polymer with (cured curing curable) 157 and polymer with (cured curing curable) 158 and polymer with (cured curing curable)

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L58	1674	(CdS or CdSe or CdTe or ZnS or ZnSe or ZnTe or HgS or HgSe or HgTe or GaN or GaP or GaAs or InP or InAs) with (nanoparticle nanocrystal)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 19:35
L59	223383	(cross-link crosslink cross-linked	US-PGPUB;	OR	OFF	2006/08/12 19:35
4.	h	cross-linking)	USPAT; EPO;			
			DERWENT;			
		شود م رشور ه و بهدید که داده داده داده داده داده داده داده	IBM_TDB_			
L60	412	L58 and L59	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L61	183	(cross-link crosslink cross-linked	US-PGPUB;	OR	OFF"	2006/08/12 19:35
		cross-linking) with photocurable	USPAT; EPO;			
			DERWENT;			
			IBM_TDB			
L62	28415	(cross-link crosslink cross-linked cross-linking) with (uv cure curing curable cured photocurable)	US-PGPUB; USPAT; EPO; DERWENT;	OR	OFF	2006/08/12 19:35
L63	955	L58 and (uv cure curing curable	IBM_TDB			Madala Ana Sana Sana Sana Sana Sana Sana Sana
105	933	cured photocurable)	US-PGPUB; USPAT;	OR	OFF	2006/08/12 19:35
			EPO;			
		[경기 :	DERWENT; IBM_TDB			
L64	338	(cross-link crosslink cross-linked	US-PGPUB;	OR	OFF	2006/08/12 19:35
		cross-linking) and L63	USPAT; EPO; DERWENT; IBM_TDB		3.1	2000/00/12 19.33
L65	37809	(cross-link cross-linked	US-PGPUB;	OR	OFF.	2006/08/12 19:35
		cross-linking) same (uv cure curing curable cured photocurable)	USPAT; EPO;			
			DERWENT;			
			IBM_TDB			
L66	86	"5,906,670" "5,888,885" "5,229, 320" "5,482,890"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L67	66661	(cross-link cross-linked cross-linking	US-PGPUB;	OR	ÔN	2006/08/12 19:35
		crosslinking crosslinked crosslinks crosslink) and @pd<"19880101"	USPAT; EPO;			
	-		DERWENT; IBM_TDB			

	L68	581	UV with (cured curing curable) and L67	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35	!
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